DP3T USB Type C Audio and UART Analog Switch with OVP

Description

The FSA1153 is a bi-directional, low power, high speed USB2.0 Type-C, Audio and UART analog switch with overvoltage protection. It is configured as a Double-Pole, Triple Throw (DP3T) switch. The FSA1153s protection function prevents damage to Type-C USB 2.0 port pins caused by high voltage. It provides a receptacle side OVP function on the USB 2.0 data pins and will turn off the relative switch once the voltage level on DN_L or DP_R exceed the OV threshold. It can withstand up to 20.5 V DC.

Features

- DP3T USB Type C Audio and UART Analog Switch
- V_{DD}: 2.7 V to 5.5 V
- I_{CC}: 35 μA Typical
- USB Switch
 - ◆ -3 dB Bandwidth (Sdd21): 850 MHz
- Audio Switch:
 - ◆ Negative Rail Capability: -3 V to +3 V
 - Audio Path $R_{ON} = 1 \Omega$ (Typ.) at 3.3 V
- UART Switch:
 - RON: 5 Ω (Typ.) at 3.3 V
 - ◆ Signal Range: 0 4.4 V
- High Power Supply Ripple Rejection
- 20.5 V Overvoltage Protection on DN_L/DP_R
- 20.5 V Surge Protection on DN L/DP R

Applications

- Mobile Phones
- Tablets
- Notebook PC
- Media Player



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WLCSP12 CASE 567WM

MARKING DIAGRAM

6GKK XYZ

6G = Device Number
KK = Assembly Lot
X = Year
Y = Work Week
Z = Assembly Location

ORDERING INFORMATION

See detailed ordering and shipping information on page 3 of this data sheet.

Typical Application

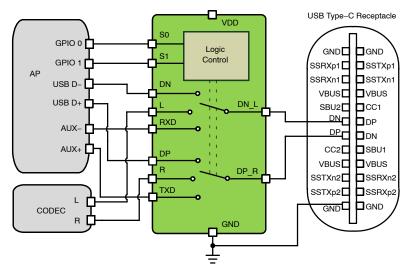


Figure 1. Typical Application

Pin Definitions

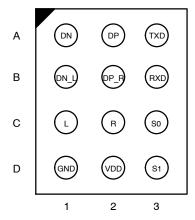


Figure 2. Top Through View

PIN DESCRIPTION

Pin	Name	Description
A1	DN	USB Data (Differential –)
A2	DP	USB Data (Differential +)
A3	TXD	UART Transmit Data
B1	DN_L	USB/Audio/UART Common Connector
B2	DP_R	USB/Audio/UART Common Connector
В3	RXD	UART Receive Data
C1	L	Audio – Left Channel
C2	R	Audio – Right Channel
СЗ	S0	Data Switch Select
D1	GND	Chip Ground
D2	VDD	Power Supply (2.7 to 5.5 V)
D3	S1	Data Switch Select

Table 1. CONTROL LOGIC STATUS

S1	S0	USB Switch	Audio Switch	UART Switch
0	0	ON	OFF	OFF
0	1	OFF	ON	OFF
1	0	OFF	OFF	ON
1	1	Disable	Disable	Disable

ORDERING INFORMATION

Part Number	Operating Temperature Range	Package	Top Mark
FSA1153UCX	−40 to +85°C	12-Ball WLCSP, Non-JEDEC 1.45 mm x 1.615 mm, 0.4 mm Pitch	6G

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ABSOLUTE MAXIMUM RATINGS

Symbol		Parameter	Min.	Max.	Unit
VDD	Supply Voltage from VDD		-0.5	6.5	V
V _{SW_C}	V _{DP_R} to GND, V _{DN_L} to GND (Note 1)		-3.6	20.5	V
V _{SW_USB}	V _{DP} to GND, V _{DN} to GND (Note 1)		-0.5	6.5	V
V _{SW_Audio}	V _L to GND, V _R to GND (Note 1)		-3.6	6.5	V
V _{SW_UART}	V _{TXD} to GND, V _{RXD} to GND (Note 1)		-0.5	6.5	V
V _{SW}	Control Input Voltage: S1, S0 (Note 2)		-0.5	6.5	V
I _{SW_Audio}	Switch I/O Current, Audio path: R, L, DP_R, DN_L		-250	250	mA
I _{SW_USB}	Switch I/O Current, USB path; DP to DP_R, DN to DN_L		-	100	mA
I _{SW_UART}	Switch I/O Current, UART path; TXD to DP_R, RXD to DN_L		-	50	mA
I _{IK}	DC Input Diode Current		-50	-	mA
ESD	Human Body Model,	Connector side and power pins: VDD, DP_R, DN_L	4	-	kV
	ANSI / ESDÁ / JEDÉC JS-001-2012	Host side pins: The rest pins	2	-	
	Charged Device Model, JEDEC: JESD22-C101		1	_	
Surge	IEC 61000-4-5 System Connector side pins: DP_R, DN_L		-20.5	+20.5	V
T _A	Absolute Maximum Operating Temperature		-40	+85	°C
T _{STG}	Storage Temperature		-65	+150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

2. V_{SW} refers to analog data switch paths.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Тур	Max	Unit
POWER					
VDD	Supply Voltage	2.7	_	5.5	V
USB SWITC	CH				
V _{SW_USB}	V_{DP} to GND, V_{DN} to GND, V_{DP_R} to GND, V_{DN_L} to GND	0	_	4.5	V
AUDIO SWI	тсн				
V _{SW_Audio}	V_{DP_R} to GND, V_{DN_L} to GND, V_L to GND, V_R to GND,	-3.0	_	+3.0	V
UART SWIT	СН				
V _{SW_UART}	V _{TXD} to GND, V _{RXD} to GND	0	_	4.4	V
OPERATING	G TEMPERATURE				
T _A	Ambient Operating Temperature	-40	25	+85	°C
CONTROL	CONTROL VOLTAGE (S1, S0)				
V _{IH}	Input Voltage High	1.3	_	VCC	V
V _{IL}	Input Voltage Low	0	-	0.5	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC AND TRANSIENT CHARACTERISTICS

 $(V_{DD}=2.7~V~to~5.5~V.~V_{DD}(Typ.)=3.3~V,~T_{A}=-40^{\circ}C~to~85^{\circ}C,~and~T_{A}~(Typ.)=25^{\circ}C,~unless~otherwise~specified)$

				T _A = -	40°C to	85°C	
Symbol	Parameter	Condition	Power	Min	Тур	Max	Unit
GENERAL	DEVICE PINS						
I _{CC}	Supply current	For all switches	VDD: 2.7 to 5.5	-	-	35	μΑ
I _{CCZ}	Quiescent current	S0, 1 = 1		_	_	3	1
I _{CCT}		Vin = 1.5 V		-	10	-	μΑ
СОММОИ	PINS: DP_R, DN_L						
I _{OZ}	Off leakage current of Port DP_R and DN_L	DP_R, DN_L = -3 V to 4.0 V	VDD: 2.7 to 5.5	-3.0	0.1	3.0	μΑ
l _{OFF}	Power-Off leakage current of Port DP_R and DN_L	DP_R, DN_L = 0 V to 4.0 V	Power off	-3.0	0.1	3.0	μΑ
V _{OV_TRIP}	Input OVP Lockout	Sweep from 3 V to 6 V	VDD: 2.7 to 5.5	4.7	5.0	5.3	V
V _{OV_HYS}	Input OVP Hysteresis		VDD: 2.7 to 5.5	0.2	0.3	0.4	V
AUDIO SW	итсн						
I _{ON}	On leakage current of Audio switch	DN_L, DP_R = -3 V to 3.0 V, R, L = Float	VDD: 2.7 to 5.5	-2.0	0.1	2.0	μΑ
l _{OZ}	Off leakage current of	L/R = -3 V to 3.0 V	VDD: 2.7 to 5.5	-1	0.1	1	μА
l _{OFF}	Input Leakage Current , Power off	L, R = 0 to 3 V, DP_R, DP_L = Float, (I _{SW} = 0 mA)	Power off	-1.0	0.1	1.0	μΑ
R _{ON}	Switch On Resistance	I _{SW} = 100 mA, V _{SW} = -3 V to 3 V	VDD: 2.7 to 5.5	_	1	2	Ω
ΔR_{ON}	On Resistance Matching, Channel to Channel	I _{SW} = 100 mA, V _{SW} = -3 V to 3 V	VDD: 2.7 to 5.5	_	0.1	0.2	Ω
R _{FLAT}	On Resistance Flatness	I _{SW} = 100 mA, V _{SW} = -3 V to 3 V	VDD: 2.7 to 5.5	_	10	_	mΩ
USB SWIT	СН						
I _{ON}	On leakage current of USB switch	DN_L, DP_R = 0 V to 3.6 V, DP = DN = Float	VDD: 2.7 to 5.5	-3.0	0.1	5	μΑ
		DN_L, DP_R = 3.6 V to 4.5 V, DP = DN = Float		-5	_	15	μΑ
l _{OZ}	Off leakage current of Port DP and DN	DN, DP = 0 V to 4.5 V	VDD: 2.7 to 5.5	-3.0	0.1	3.0	μΑ
I _{OFF}	Power-Off leakage current of Port DP and DN	DN, DP = 0 V to 4.5 V	Power off	-3.0	0.1	3.0	μΑ
R _{ON_USB}	Switch On Resistance	$V_{SW} = 0.4 \text{ V}, I_{ON} = -8 \text{ mA}$	VDD: 2.7 to 5.5	_	3	5	Ω
		$Vsw = 4.0 V, I_{ON} = -8 mA$		_	3	5	
UART SWI	тсн						
I _{ON}	On leakage current of UART switch	DN_L, DP_R = 0 V to 4.4 V, UART = Float	VDD: 2.7 to 5.5	-3.0	0.1	15	μΑ
l _{OZ}	Off leakage current of Port TXD and RXD	TXD/RXD = 0 V to 4.4 V,	VDD: 2.7 to 5.5	-3.0	0.1	3.0	μΑ
I _{OFF}	Power-Off leakage current of Port TXD/RXD	TXD/RXD = 0 V to 4.4 V,	Power off	-3.0	0.1	3.0	μΑ
R _{ON_UART}	UART Switch On Resistance	$V_{SW} = 0$ to 4.4 V, $I_{ON} = -8$ mA	VDD: 2.7 to 5.5	_	5	7	Ω
S1, S0							
V _{IH}	Input Voltage High		VDD: 2.7 to 5.5	1.3	_	VDD	V
V_{IL}	Input Voltage Low		VDD: 2.7 to 5.5	_	_	0.5	V
R _{PD}	Internal Pull down resistor on S1,S0	S1, S0 = VDD	VDD: 2.7 to 5.5	_	3	-	МΩ

AC CHARACTERISTICS

 $(V_{DD}=2.7~V~to~5.5~V.~V_{DD}(Typ.)=3.3~V,~T_{A}=-40^{\circ}C~to~85^{\circ}C.~T_{A}~(Typ.)=25^{\circ}C,~unless~otherwise~specified)$

					T _A = -	-40°C to	85°C	Unit
Symbol	Parameter	Condition		Power	Min	Тур	Max	Unit
AUDIO PA	ATH SWITCH				-			
t _{ON}	Turn On Time (Note 3)	$DP/R = DN/L = 0 V \rightarrow to 1 V, L, R =$: 32 Ω to GND		_	80	_	μs
t _{OFF}	Turn OFF Time (Note 3)	DP/R = DN/L = 1 V fall to GND, L, F	$R = 32 \Omega$ to GND		-	0.4	-	μs
t _{BBM}	Break Before Make (Note 3)	USB \rightarrow Audio, DP/R = DN/L = 0 V - L, R = 32 Ω to GND, DP, DN = 50 Ω UART \rightarrow Audio, UART = 50 Ω	→ 1 V, ⊇ to GND		-	80	_	μs
T _{EN}	Enable Time (Note 3)	DP/R = DN/L = 1 V, L, R = 32 Ω to GND, S[1, 0] from 11	to 01		_	230	-	μS
T _{Dis}	Disable Time (Note 3)	DP/R = DN/L = 1 V, L, R = 32 Ω to GND, S[1, 0] from 01	l to 11		-	0.3	-	μs
t _{OVP}	Response Time	R_{LOAD} = 32 Ω , Vsw = 3 V to 6 V (slemeasure OV threshold to 90% OVP output falling	ew rate >10 V/1 μs), trigger level of		-	0.2	1	μs
O _{IRR}	Off Isolation (Note 3)	$f = 1 \text{ kHz}, R_L = 50 \Omega, C_L = 0 \text{ pF}, V_{SV}$	_W = 1 V _{RMS}		-	-100	-	dB
		$f = 1 \text{ MHz}, R_L = 50 \Omega, C_L = 0 \text{ pF}, V_S$	_W = 1 V _{RMS}			-65		
X _{TALK}	Cross Talk (Adjacent) (Note 3)	f = 1 kHz, R_L = 50 Ω , V_{SW} = 1 V_{RMS}	S		-	-120	-	dB
	Cross Talk (USB-Audio) (Note 3)	f = 1 kHz or 20 kHz, R_L = 50 Ω , V_{SV} DN	_V = 1 V _{RMS} on DP or		-	-108	-	
BW	-3 dB Bandwidth (Note 3)	R _L = 50 Ω			-	500	-	MHz
PSRR	PSRR Power Supply Rejection Ratio (Note 3)	$R_1 = 20 \text{ k}\Omega \text{ or } 32 \Omega$	$R_L = 32 \Omega$		-	-119	-	dB
			$R_L = 20 \text{ k}\Omega$		-	-105	-	1
THD+N	Total Harmonic Distortion	V _{SW} = 0.5 V _{BMS}	With A-weighted		-	-108	-	dB
	+ Noise (Note 3)		Non A-weighted		_	-105	1	
		$R_L = 32 \Omega$, $f = 20Hz \sim 20 \text{ kHz}$,	With A-weighted		-	-110	1	dB
		V _{SW} = 1 V _{RMS} Non A-			-	-105	1	
		$ \begin{array}{ll} R_L = 20 \text{ k}\Omega, \text{ f} = 20 \text{ Hz} \sim 20 \text{ kHz}, \\ V_{SW} = 0.3 \text{ V}_{RMS} \end{array} $			_	-110		dB
					_	-105	1	
USB SWIT	ГСН							
t _{ON}	Turn-on time (Note 3)	DP/R = DN/L = 1.0 V, DP, DN = 50	Ω to GND		-	40	-	μS
t _{OFF}	Turn-off time (Note 3)	DP/R = DN/L = 1.0 V, DP, DN = 50	Ω to GND		-	0.35	-	μs
T _{BBM}	Break-Before-Make (Note 3)	Audio \rightarrow USB; DP/R = DN/L = 1.5 \ L, R = 50 Ω to GND, DP, DN = 50 Ω UART \rightarrow USB: UART = 50 Ω			_	40	_	μs
T _{EN}	Enable Time (Note 3)	DP/R = DN/L = 1 V, $DP/DN = 50$ Ω S[1, 0] from 11 to 00	to GND,		_	200	-	μs
T_Dis	Disable Time (Note 3)	DP / R = DN / L = 1 V, DP / DN = 50 Ω to GND, S[1, 0] from 00 to 11			_	0.25	-	μs
BW	-3dB Bandwidth (Note 3)	RL = 50 Ω, Switch ON			-	0.85	-	GHz
X _{TALK}	Cross Talk (Adjacent) (Note 3)	RL = 50 Ω , Switch ON, f = 240 MHz			-	-40	-	dB
O _{IRR}	Off Isolation (Note 3)	RL = 50 Ω , Switch OFF, f = 240 MH	z		-	-24	-	dB
t _{OVP}	Response Time	R _{LOAD} = 50 Ω, Vsw = 3 V to 6 V (sle measure OV threshold to 90% OVP output falling			_	0.2	1	μs

AC CHARACTERISTICS (continued)

 $(V_{DD} = 2.7 \text{ V to } 5.5 \text{ V. } V_{DD}(\text{Typ.}) = 3.3 \text{ V}, T_A = -40 ^{\circ}\text{C to } 85 ^{\circ}\text{C}. T_A (\text{Typ.}) = 25 ^{\circ}\text{C}, \text{ unless otherwise specified)}$ (continued)

				T _A = -	-40°C to	o 85°C	Unit
Symbol	Parameter	Condition	Power	Min	Тур	Max	Unit
ISB SWIT	СН						
Recovery	Recovery Debounced time (Note 3)	R_{LOAD} = 50 Ω, Vsw = 6 V to 3 V (slew rate < 10 V/1 μs), measure OV threshold to 90% output rising		-	30	-	us
t _{PD}	Propagation Delay (Note 3)	$R_L = 50 \Omega$, $C_L = 5 pF$		-	100	-	ps
t _{SK(P)}	Skew of Opposite Transitions of the Same Output (Note 3)	$R_L = 50 \Omega$, $C_L = 5 pF$		_	10	-	ps
tJ	Total Jitter (Note 3)	V_{SW} = 0.4 Vdiff _{PP} , R _L = 50 Ω , C _L = 5 pF, t _R = t _F = 500 ps (10 – 90%) @ 480 Mbps (PBRS = 2^{15} – 1)		_	200	-	ps
ART SW	ІТСН						
t _{ON}	Turn-on time (Note 3)	UART = 1.8 V, Rload = 50 Ω		-	50	-	μS
t _{OFF}	Turn-off time (Note 3)	UART = 1.8 V, Rload = 50 Ω		-	0.4	-	μs
T _{BBM}	Break-Before-Make (Note 3)	USB \rightarrow UART, USB = 50 Ω , UART=50 Ω Audio \rightarrow UART		_	50	-	μS
T _{EN}	Enable Time (Note 3)	DP/R = DN/L = 1 V, DP/DN = 50 Ω to GND, S[1, 0] from 11 to 10		_	200	-	μS
T _{Dis}	Disable Time (Note 3)	DP/R = DN/L = 1 V, DP/DN = 50 Ω to GND, S[1, 0] from 10 to 11		_	300	-	μS
t _{OVP}	Response Time	R_{LOAD} = 50 $\Omega,$ Vsw = 3 V to 6 V (slew rate > 10 V/1 $\mu s),$ measure OV threshold to 90% OVP trigger level of output falling		-	0.2	1	μs
BW	Bandwidth (Note 3)	$R_1 = 50 \Omega$		_	400	_	MHz

^{3.} Guaranteed by characterization, not production tested.

$\textbf{CAPACITANCE} \ (V_{DD} = 2.7 \ V \ to \ 5.5 \ V. \ V_{DD}(Typ.) = 3.3 \ V, \ T_{A} = -40 ^{\circ}C \ to \ 85 ^{\circ}C. \ T_{A} \ (Typ.) = 25 ^{\circ}C, \ unless \ otherwise \ specified)$

					T _A = -	40°C to	85°C	
Symbol	Parameter	Condition	Pov	ver	Min	Тур	Max	Unit
AUDIO PATH SWITCH	I							
C _{ON_USB/Audio/UART}	On Capacitance (Common Port) (Note 4)	f =1MHz, 240 MHz, 100 mV $_{PK-PK}$, 100 DC bias	mV 3.	3	-	7	-	pF
C _{OFF_USB/Audio/UART}	Off Capacitance (Common Port) (Note 4)	f = 1MHz, 240MHz, 100 mV _{PK-PK} , 100 mV DC bias		3	-	7	-	pF
C _{OFF_USB}	Off Capacitance (Non-Common Ports) (Note 4)	f = 240 MHz, 100 mV _{PK-PK} , 100 mV DC bias		3	-	2.5	-	pF
C_{OFF_Audio}	Off Capacitance (Non-Common Ports) (Note 4)	f = 1 MHz, 100 mV _{PK-PK} , 100 mV DC bias		3	-	3.5	-	pF
C _{OFF_UART}	Off Capacitance (Non-Common Ports) (Note 4)	f = 1 MHz, 100 mV _{PK-PK} , 100 mV DC bias		3	-	3.5	-	pF
C _{IN}	EN,SEL Pin Capacitance (Note 4)	f = 1 MHz, 100 mV _{PP} , 100 mV DC bias	S1, S0 0)	-	2.5	-	pF

^{4.} Guaranteed by characterization, not production tested.

Application Information

Over-Voltage Protection

The FSA1153 features over-voltage protection (OVP) on the receptacle side pins DN_L and DP_R which will switch off the internal signal routing path if the input voltage exceeds the OVP threshold. When an over voltage condition has occurred the switch will open immediately and remain open until the over voltage condition is removed.

Test Diagrams

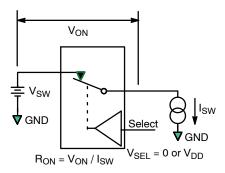


Figure 3. On Resistance

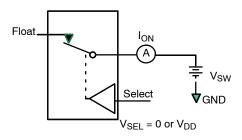


Figure 5. On Leakage

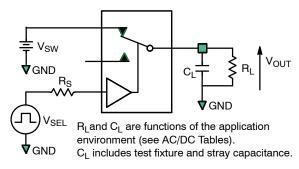


Figure 7. Test Circuit Load

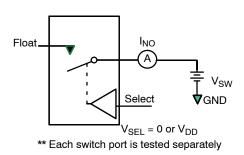


Figure 4. Off Leakage (loz)

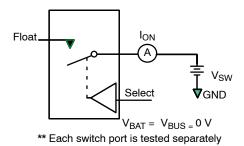


Figure 6. Power Off Leakage (loff)

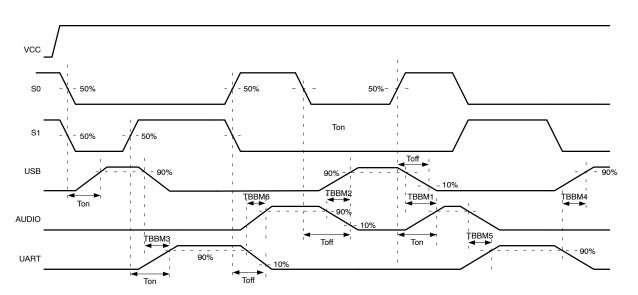


Figure 8. Timing Waveforms

Test Diagrams (continued)

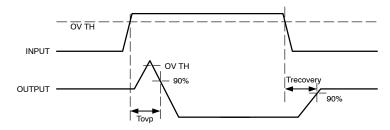


Figure 9. OVP Timing

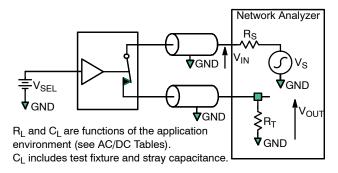


Figure 10. Bandwidth

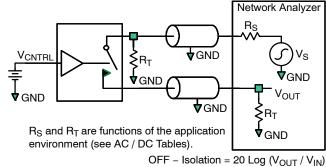


Figure 11. Channel Off Isolation

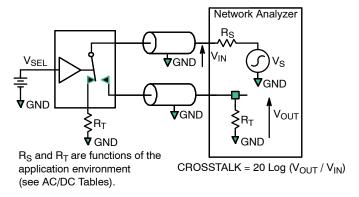


Figure 12. Adjacent Channel Crosstalk

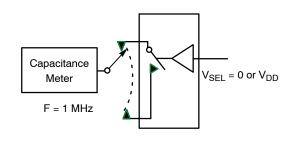


Figure 13. Channel Off Capacitance

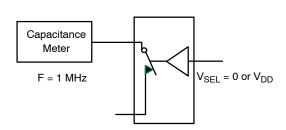


Figure 14. Channel On Capacitance

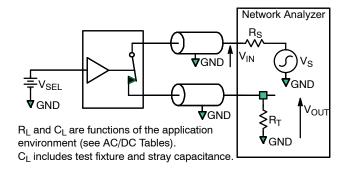
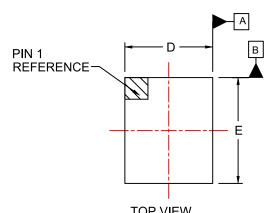


Figure 15. Total Harmonic Distortion (THD+N)



WLCSP12, 1.41x1.575x0.599 CASE 567WM ISSUE O

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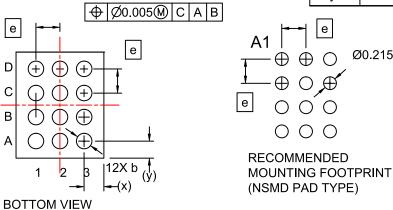
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DATUM C APPLIES TO THE SPHERICAL CROWN OF THE SOLDER BALLS

TOP VIEW	
DETAIL A	/ A2
0.05 C A	$\frac{A1}{1}$
SEATING PLANE	C DETAIL A
SIDE VIEW	

98AON92156G

	MILLIMETERS				
DIM	MIN.	NOM.	MAX.		
Α	0.561	0.599	0.637		
A1	0.174	0.194	0.214		
A2	0.387	0.405	0.423		
b	0.240	0.260	0.280		
D	1.380	1.410	1.440		
Е	1.545	1.575	1.605		
е	0.40 BSC				
х	0.290	0.305	0.320		
у	y 0.1725 0.1875 0.20				



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DESCRIPTION: WLCSP12, 1.41x1.575x0.599 **PAGE 1 OF 1**

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